

ESD Protection Diodes Silicon Epitaxial Planar

DF2B7M3SL

General

The DF2B7M3SL is a TVS diode (ESD protection diode) protects semiconductor devices used in mobile device interfaces and other applications to protect against static electricity and noise.

The DF2B7M3SL provide to protect the latter part well by the low dynamic resistance, improve the system reliability level by the high $V_{\rm ESD}$ performance. Furthermore, it is optimum for antenna application for the low capacitance performance.

The DF2B7M3SL is housed in an ultra-compact package (0.62 mm \times 0.32 mm) to meet applications that require a small footprint.

2. Applications

Mobile Equipment

- · Smartphones
- · Tablets
- · Notebook PCs

Desktop PCs

Note: This product is designed for protection against electrostatic discharge (ESD) and is not intended for any other purpose, including, but not limited to, voltage regulation.

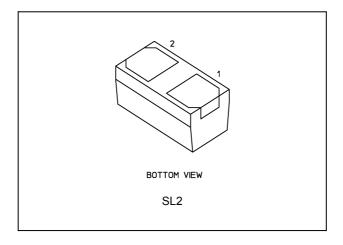
3. Features

- (1) Suitable for use with a 5 V signal line. $(V_{RWM} \le 5.5 \text{ V})$
- (2) Protects devices with its high ESD performance. $(V_{\rm ESD} = \pm 12 \text{ kV (Contact)}, V_{\rm ESD} = \pm 15 \text{ kV (Air) @IEC61000-4-2})$
- $(3) \quad Low \ dynamic \ resistance \ protects \ semiconductor \ devices \ from \ static \ electricity \ and \ noise.$

 $(R_{DYN} = 0.7 \Omega \text{ (typ.)})$

(4) Compact package is suitable for use in high density board layouts such as in mobile devices. (0.62 mm × 0.32 mm size (Nickname: SL2))

4. Packaging

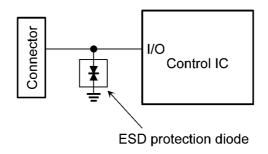


Start of commercial production

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5. Example of Circuit Diagram



6. Quick Reference Data

Characteristics	Symbol	Note	Test Condition		Тур.	Max	Unit
Working peak reverse voltage	V_{RWM}	(Note 1)	_	_		5.5	V
Total capacitance	Ct		V _R = 0 V, f = 1 MHz		0.1	0.2	pF
			V _R = 0 V, f = 5 GHz	_	0.1	_	
Dynamic resistance	R_{DYN}	(Note 2)	_	_	0.7	_	Ω
Electrostatic discharge voltage (IEC61000-4-2) (Contact)	V _{ESD}	(Note 3)	_			12	kV

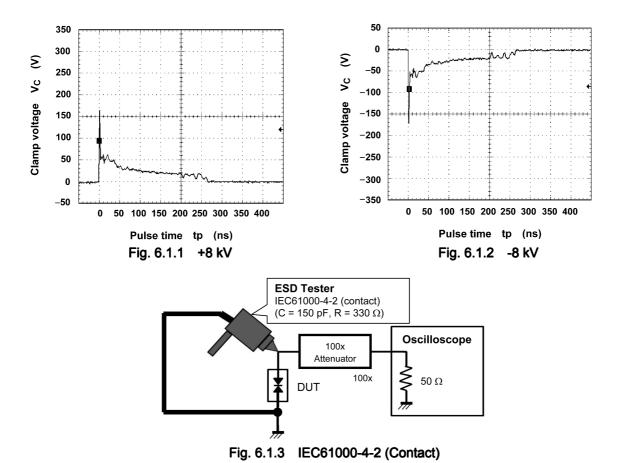
Note 1: Recommended operating condition.

Note 2: TLP parameters: $Z0 = 50 \Omega$, tp = 100 ns, tr = 300 ps, averaging window: t1 = 30 ns to t2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristics between $I_{PP1} = 8$ A and $I_{PP2} = 16$ A.

Note 3: Criterion: No damage to devices.

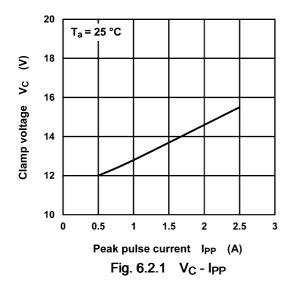


6.1. ESD Clamp Waveform (Note)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

6.2. Clamp Voltage - Peak Pulse Current (VC - IPP) (Note)



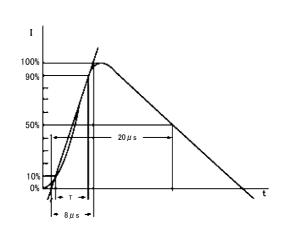


Fig. 6.2.2 Based on IEC61000-4-5 8/20 μs pulse.

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Electrostatic discharge voltage (IEC61000-4-2) (Contact)	V _{ESD}	(Note 1)	±12	kV
Electrostatic discharge voltage (IEC61000-4-2) (Air)			±15	
Peak pulse power (tp = 8/20 μs)	P _{PK}		50	W
Peak pulse current (tp = 8/20 μs)	I _{PP}	(Note 2)	2.5	Α
Junction temperature	Tj		150	°C
Storage temperature	T _{stg}		-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: According to IEC61000-4-2. Note 2: According to IEC61000-4-5.

8. Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

 V_{RWM} : Working peak reverse voltage V_{BR} : Reverse breakdown voltage I_{BR} : Reverse breakdown current

I_R: Reverse current V_C: Clamp voltage I_{PP}: Peak pulse current R_{DYN}: Dynamic resistance

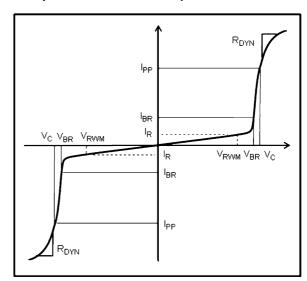


Fig. 8.1 Definitions of Electrical Characteristics

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Working peak reverse voltage	V_{RWM}	(Note 1)	_	_	_	5.5	V
Total capacitance	Ct		V _R = 0 V, f = 1 MHz	_	0.1	0.2	pF
			V _R = 0 V, f = 5 GHz	_	0.1	_	
Dynamic resistance	R _{DYN}	(Note 2)	_		0.7	_	Ω
Reverse breakdown voltage	V_{BR}		I _{BR} = 1 mA	6	_	11	V
Reverse current	I _R		V _{RWM} = 5.5 V	_	_	0.5	μΑ
Clamp voltage	V _C	(Note 3)	I _{PP} = 1 A	_	13	_	V
			I _{PP} = 2.5 A		15.5	20	

Note 1: Recommended operating condition.

Note 2: TLP parameters: $Z0 = 50 \Omega$, tp = 100 ns, tr = 300 ps, averaging window: t1 = 30 ns to t2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristics between $I_{PP1} = 8$ A and $I_{PP2} = 16$ A.

Note 3: Based on IEC61000-4-5 8/20 μ s pulse.



9. Characteristics Curves (Note)

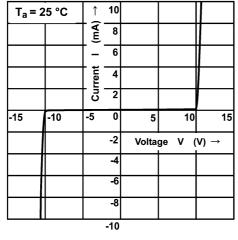
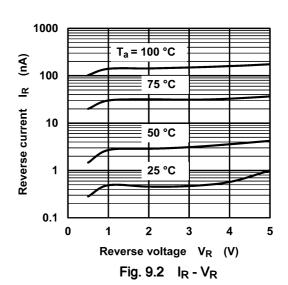
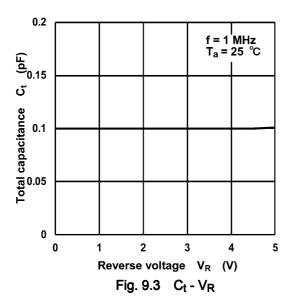
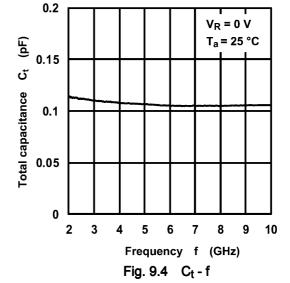
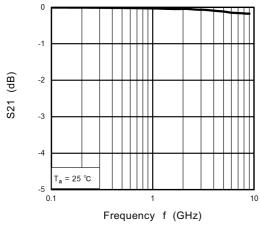


Fig. 9.1 I-V

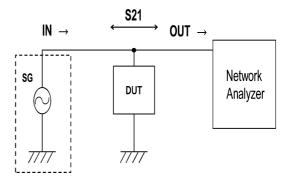








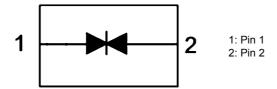




Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

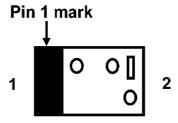


10. Internal Circuit (Note)

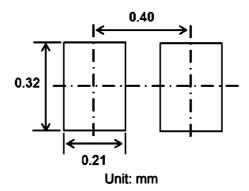


Note: Connect Pin 2 to GND when using Pin 1 for I/O. Connect Pin 1 to GND when using Pin 2 for I/O.

11. Marking (Top view)



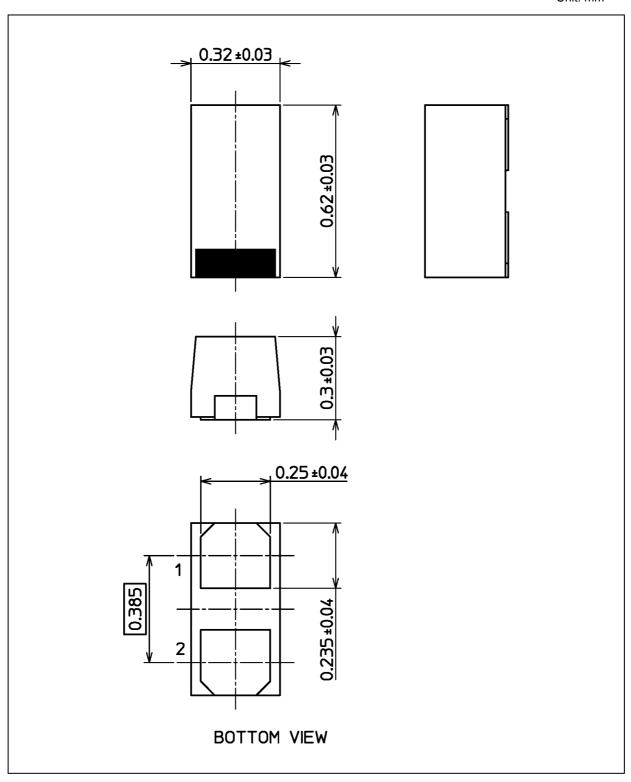
12. Land Pattern Dimensions (for reference only)





Package Dimensions

Unit: mm



Weight: 0.2 mg (typ.)

	Package Name(s)	
Nickname: SL2		

Rev.3.0



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